

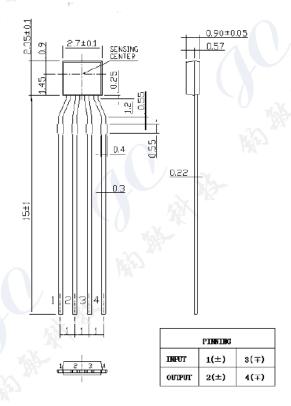
MW921 InSb Hall Element

Ultra High-sensitivity InSb Hall element

Thin-type SIP Package

Shipped in Bulk by Pack (500Pcs devices per pack)

Dimensional Drawing (Unit MM)



Absolute Maximum Rating

Operating Temperature Range -40° C ~ 110°CStorage Temperature Range -40° C ~ 125°CMaximum Input Current l_{cmax} [mA]10mA

Electrical Characteristic (RT=25°C)

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Table 1. Electrical Characteristics of MW921							
ltem	Symbol	Test Condi.	Min.	Тур.	Max.	Unit	
Hall Voltage	K	B = 50mT, V _C =1V T _a = RT	168		320	mV	
Input Resistance	R _{in}	$B = 0$ mT, $I_{c} = 0.1$ mA $T_{a} = RT$	240		550	Ω	
Output Resistance	R _{out}	\boldsymbol{B} = 0mT, \boldsymbol{I}_{c} = 0.1mA \boldsymbol{T}_{a} = RT	240		550	Ω	
Offset Voltage	V _{os}	\boldsymbol{B} = 0mT, \boldsymbol{V}_{C} = 1V \boldsymbol{T}_{a} = RT	-7		+7	mV	
Temp. Coeffi. of V_{H}	$ \alpha V_{H} $	$B = 50 \text{mT}, I_{\text{C}} = 1 \text{mA},$ $T_{\text{a}} = 0^{\circ}\text{C} \sim 40^{\circ}\text{C}$		1.8		%/°C	
Temp. Coeffi. of R _{in}	α R in	$B = 50 \text{mT}, I_{\text{C}} = 5 \text{mA},$ $T_{\text{a}} = 0^{\circ}\text{C} \sim 40^{\circ}\text{C}$		-1.8	N.	%/°C	
Dielectric strength		100V D.C	1.0			MΩ	

 $V_{\rm H} = V_{\rm H-M} - V_{\rm os}$ in which $V_{\rm H-M}$ is the Output Hall Voltage, $V_{\rm H}$ is the Hall Voltage and $V_{\rm os}$ is the offset Voltage under the identical electrical stimuli.

2.
$$\alpha V_H = \frac{1}{V_H(T_1)} \times \frac{V_H(T_3) - V_H(T_2)}{(T_3 - T_2)} \times 100$$

3.
$$\alpha R_{in} = \frac{1}{R_{in}(T_1)} \times \frac{R_{in}(T_3) - R_{in}(T_2)}{(T_3 - T_2)} \times 100$$

 $T_{1=20^{\circ}\text{C}}, T_{2=0^{\circ}\text{C}}, T_{3=40^{\circ}\text{C}}$

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Classification of Output Hall Voltage ($\textit{V}_{\textrm{H}}$)

Table 2. Classification of Hall Voltage				
Rank	V _H [mV]	Conditions		
С	168 ~ 204	B=50mT, V c=1V		
D	196 ~ 236			
E	228 ~ 274			
F	266 ~ 320			
20				

Characteristic Curves

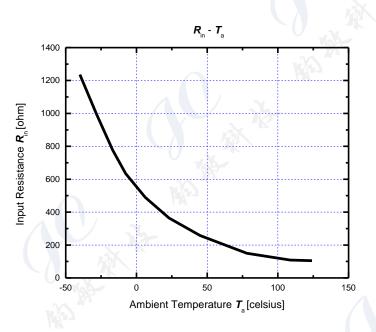
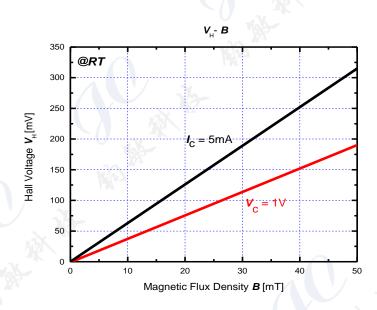


Figure 1. Input resistance R_{in} as a function of ambient temperature T_{a} .

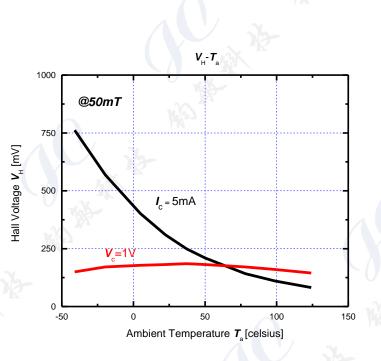
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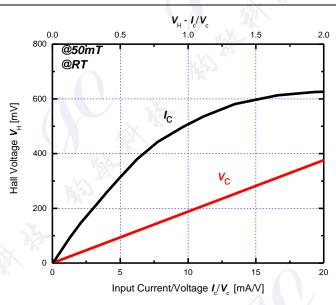


Figure 4. Hall voltage $V_{\rm H}$ as a function of electrical stimuli $I_{\rm c}/V_{\rm c}$.

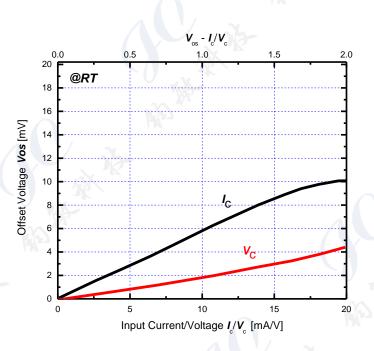


Figure 5. Offset voltage V_{os} as a function of electrical stimuli I_c/V_c .

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Precautions for ESD

This product is the device that is sensitive to ESD (Electrostatic Discharge). Handling Hall Elements with the ESD-Caution mark under the environment in which

- Static electrical charge is unlikely to arise. (Ex; Relative Humidity; over 40%RH).
- Wearing the antistatic suit and wristband when handling the devices.
- Implementing measures against ESD as for containers that directly touch the devices.

Precautions for Storage

- Products should be stored at an appropriate temperature and humidity (5 to 35°C, 40 to 60%RH) after the unsealing of MBB. Using self-sealer is highly recommended. Keeping products away from chlorine and corrosive gas.
- For storage longer than 2 years, it is recommended to store in nitrogen atmosphere with MBB sealed.
 Oxygen and H₂O of atmosphere oxidizes leads of products and lead solder ability get worse.

Precautions for Safety

- Do not alter the form of this product into a gas, powder or liquid through burning, crushing or chemical processing.
- Observe laws and company regulations when discarding this product.

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